

Specifications	
Part Number	S3B-E3/9AT
Manufacturer	Vishay / Semiconductor - Diodes Division
Description	DIODE GEN PURP 100V 3A DO214AB
Category	Discrete Semiconductor Products > Diodes - Rectifiers -
Part Status	2524 pcs Stock
Voltage - Forward (Vf) (Max) @ If	1.15V @ 2.5A
Voltage - DC Reverse (Vr) (Max)	100V
Supplier Device Package	DO-214AB, (SMC)
Speed	Standard Recovery >500ns, > 200mA (Io)
Series	-
Reverse Recovery Time (trr)	2.5µs
Packaging	Tape & Reel (TR)
Package / Case	DO-214AB, SMC
Operating Temperature - Junction	-55°C ~ 150°C
Mounting Type	Surface Mount
Diode Type	Standard
Current - Reverse Leakage @ Vr	10µA @ 100V
Current - Average Rectified (Io)	3A
Capacitance @ Vr, F	60pF @ 4V, 1MHz

In:

S3B-M3/57T
Vishay Semiconductor Diodes
Division
DIODE GPP 3A 100V DO-214AB



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 DIODE GEN PURP 100V 3A
 DO214AB

S3B-E3/57T IC
VISHAY
VISHAY DO-214AB



S3B-EH(LF)(SN)
JST Sales America Inc.
CONN HEADER EH SIDE 3POS
2.5MM



More

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